#### SILICON CARBIDE (SiC) SCHOTTKY DIODE ▲ B2D16120HC1

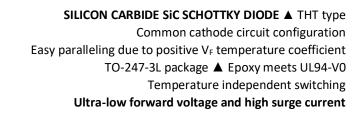


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# B2D16120HC1

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# 1200V A 2x8A A SIC SCHOTTKY DIODE







HALOGEN

FREE



Item (T <sub>c</sub> = 25°C, unless otherwise noted)	Characteristics	
Operating Temperature Range	TJ	-55°C to +175°C
Storage Temperature Range	Ts	-55°C to +175°C
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	1200V
Continuous Forward Current at $T_c = 160^{\circ}C^{Note 1}$	I <sub>F</sub>	8A
Continuous Forward Current at $T_c = 160^{\circ}C^{Note 2}$	I <sub>F</sub>	16A
Total Capacitive Charge (T <sub>J</sub> = 25°C) Note 2	Qc	96nC
Diode Forward Voltage (T <sub>J</sub> = 175°C, $I_F$ = 8A) <sup>Note 1</sup>	V <sub>F</sub>	1.34V
Power Dissipation Note 1	Ρ <sub>τοτ</sub>	170W

#### Notes

1: Per leg

2: Per device

# **APPLICATIONS**

EV Charging	Industrial Inverters	Motors & Drives	Power Factor Correction	Renewable Energy	SMPS	UPS
∳Ղ⊧	0		PFC	*		

# **PIN DESCRIPTION**

Circuit Diagram	Outline - Front View	Pin No.	Description
Backside		1 2 3	Anode Diode 1 Common Cathode (Backside) Anode Diode 2

B2D16120HC1 ▲ Rev.001 ▲ Date: 30/09/2022 ▲ Page: 1

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# **ABSOLUT MAXIMUM RATINGS A** T<sub>c</sub> = 25°C, unless otherwise noted

ltem	Condition	Symbol		Unit
Repetitive Peak Reverse Voltage		V <sub>RRM</sub>	1200	V
Non-Repetitive Peak Reverse Voltage		V <sub>RSM</sub>	1200	V
Continuous Forward Current	T <sub>c</sub> = 25°C	I <sub>F</sub>	33 Note 1 / 66 Note 2	А
Continuous Forward Current	T <sub>C</sub> = 160°C	I <sub>F</sub>	8 Note 1 / 16 Note 2	А
Non-Repetitive Forward Surge Current	$T_{C}$ = 25°C, $t_{p}$ = 10ms, Half Sine Wave	I <sub>FSM</sub>	80 Note 1	А
I <sup>2</sup> t Value	T <sub>c</sub> = 25°C, t <sub>p</sub> = 10ms	∫i²dt	32 Note 1	A <sup>2</sup> s
Power Dissipation	T <sub>c</sub> = 25°C	P <sub>TOT</sub>	170 Note 1	W
Power Dissipation	T <sub>C</sub> = 110°C	P <sub>TOT</sub>	74 Note 1	W
Operating Junction Temperature		TJ	-55 to +175	°C
Storage Temperature Range		T <sub>STG</sub>	-55 to +175	°C
TO-247 Mounting Torque	M3 Screw		0.7	Nm

#### Notes

1: Per leg

2: Per device

# **ELECTRICAL CHARACTERISTICS ▲ PER LEG**

ltem	Condition	Symbol	Min.	Тур.	Max.	Unit
Static Characteristics						
DC Blocking Voltage	T <sub>J</sub> = 25°C	V <sub>DC</sub>	1200			V
Diode Forward Voltage	I <sub>F</sub> = 8A, T <sub>J</sub> = 25°C	VF		1.34	1.60	V
Diode Forward Voltage	I <sub>F</sub> = 8A, T <sub>J</sub> = 175°C	VF		1.82	2.70	V
Reverse Current	V <sub>R</sub> = 1200V, T <sub>J</sub> = 25°C	I <sub>R</sub>		10	100	μA
Reverse Current	V <sub>R</sub> = 1200V, T <sub>J</sub> = 175°C	I <sub>R</sub>		30	300	μA
Item	Condition	Symbol	Min.	Тур.	Max.	Unit
Dynamic Characteristics						
	V <sub>R</sub> = 800V, T <sub>J</sub> = 25°C					
Total Capacitive Charge	$Q_C = \int_0^{V_R} C(V) dV$	Qc		48		nC
Total Capacitance	$V_{R} = 1V$ , f = 1MHz, T <sub>J</sub> = 25°C	С		542		рF
Total Capacitance	V <sub>R</sub> = 400V, f = 1MHz, T <sub>J</sub> = 25°C	С		46		рF
Total Capacitance	V <sub>R</sub> = 800V, f = 1MHz, T <sub>J</sub> = 25°C	С		35		рF

# THERMAL RESISTANCE PERFORMANCE

Item	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance, Junction to Case, per Leg	$R_{\theta,JC}$		0.880		K/W
Thermal Resistance, Junction to Case, per Device	$R_{\theta,JC}$		0.440		K/W

B2D16120HC1 A Rev.001 A Date: 30/09/2022 A Page: 2

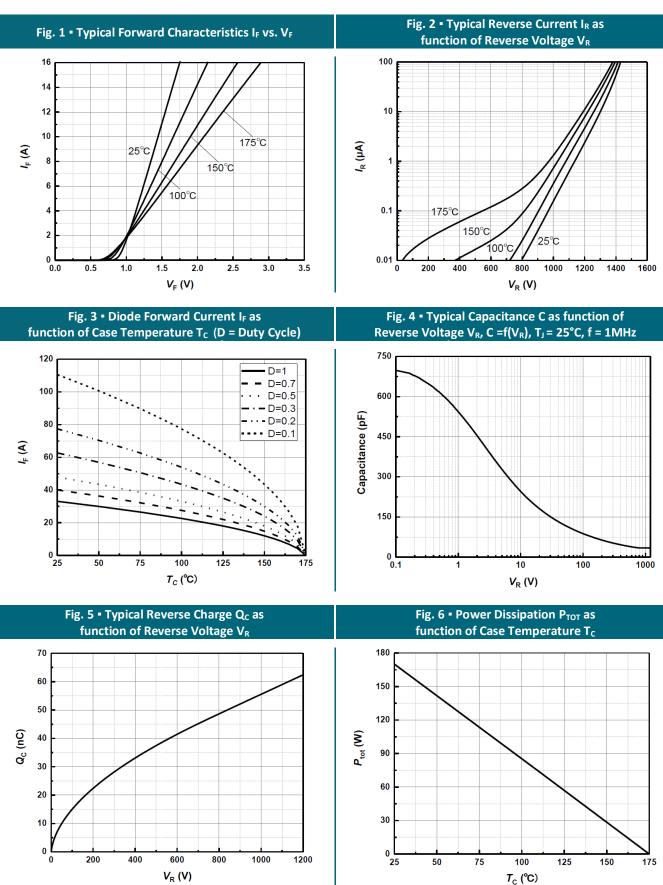
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## **REFERENCE DATA ▲ TYPICAL PERFORMANCE PER LEG**



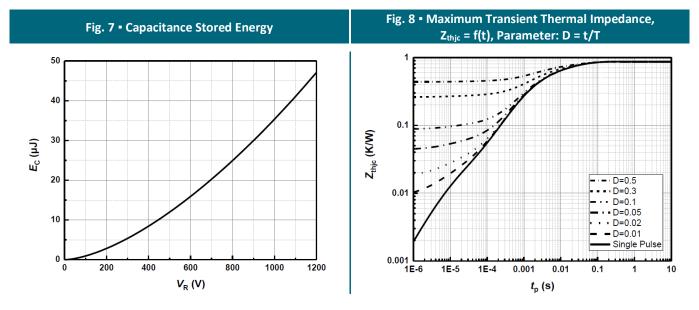
B2D16120HC1 A Rev.001 Date: 30/09/2022 Page: 3

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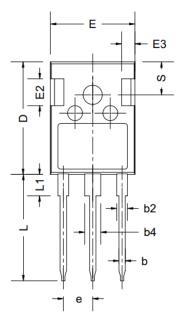
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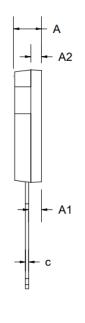
# **REFERENCE DATA ▲ TYPICAL PERFORMANCE PER LEG**

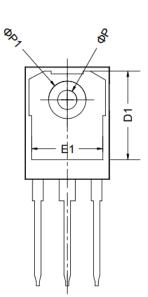




# **PACKAGE OUTLINE**







Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)	Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
А	4.80	5.00	5.20	E1	13.00	13.30	13.60
A1	2.21	2.41	2.59	E2	4.80	5.00	5.20
A2	1.85	2.00	2.15	E3	2.30	2.50	2.70
b	1.11	1.21	1.36	е		5.44 BSC	
b2	1.91	2.01	2.21	L	19.62	19.92	20.22
b4	2.91	3.01	3.21	L1	-	-	4.30
с	0.51	0.61	0.75	ØР	3.40	3.60	3.80
D	20.80	21.00	21.30	ØP1	-	-	7.30
D1	16.25	16.55	16.85	S		6.16 BSC	
E	15.50	15.80	16.10				

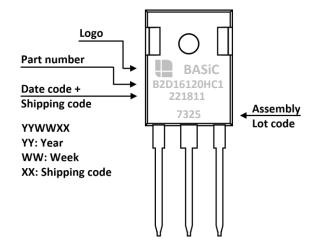
# **ORDERING INFORMATION**

Part Number	Package	Packing	Tube Qty.	Inner Box Qty.	Outer Box Qty.
B2D16120HC1	TO-247-3L	Tube	30pcs	600pcs	3,000pcs

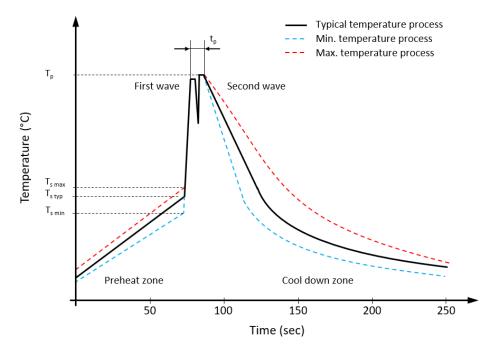


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### **PART MARKING**



# **RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE**



#### Classification wave soldering profile **A** Refer to EN 61760-1: 2006

Profile Features		Value 🔺 Sn-Pb Assembly	Value 🔺 Pb-free Assembly
Preheat temperature min.	$T_{smin}$	100 °C	100 °C
Preheat temperature typical	T <sub>s typ</sub>	120 °C	120 °C
Preheat temperature max.	$T_{s max}$	130 °C	130 °C
Preheat time $t_s$ from $T_{s min}$ to $T_{s max}$	ts	70 seconds	70 seconds
Peak temperature	Tp	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	tp	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second

B2D16120HC1 ▲ Rev.001 ▲ Date: 30/09/2022 ▲ Page: 6

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## **REVISION TABLE**

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

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